TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

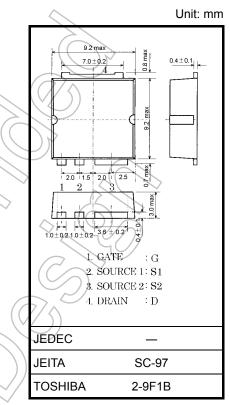
2SK3443

Switching Regulator, DC-DC Converter and Motor Drive Applications

- Low drain-source ON resistance: R_{DS (ON)} = 50 mΩ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 9 S$ (typ.)
- Low leakage current: I_{DSS} = 100 μ A (V_{DS} = 150 V)
- Enhancement mode: V_{th} = 3.0 to 5.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Rating	Unit
Drain-source voltage		150	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		150	V
Gate-source voltage		<u>+</u> 30	v
DC (Note 1)	I _D	30	A
Pulse (Note 1)	I _{DP}	120	~
Drain power dissipation (Tc = 25° C)		125	W
Single pulse avalanche energy (Note 2)		468	mJ
Avalanche current) 30	A
Repetitive avalanche energy (Note 3)		12.5	mJ
Channel temperature		150)°C
Storage temperature range		-55 to 150	°C
	$\frac{DC}{SS} = 20 \text{ k}\Omega$ $\frac{DC}{Pulse (Note 1)}$ $\frac{DC}{Pulse (Note 1)}$ $\frac{DC}{Seenergy}$ $(Note 2)$ $\frac{DC}{Seenergy}$	V_{DSS} $SS = 20 \text{ k}\Omega)$ V_{DGR} V_{GSS} $DC (Note 1)$ I_D $Pulse (Note 1)$ I_DP $r(Tc = 25^{\circ}C)$ P_D $e energy$ $(Note 2)$ E_{AS} I_{AR} T_{ch}	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$



Weight: 0.74 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	Rth (ch-c)	1.00	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2 $V_{DD} = 50 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$ (initial), L = 773 $\mu\text{H}, \text{ R}_{G} = 25 \Omega, \text{ I}_{AR} = 30 \text{ A}$

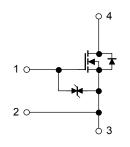
Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

Circuit Configuration

Notice:

Please use the S1 pin for gate input signal return. Make sure that the main current flows into the S2 pin.



Electrical Characteristics (Note 4) (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS}=\pm 25~V,~V_{DS}=0~V$			±10	μA
Drain cut-off curre	ent	IDSS	$V_{DS} = 150 \text{ V}, V_{GS} = 0 \text{ V}$			100	μA
Drain-source brea	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	150		_	V
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	3.0	_	5.0	V
Drain-source ON	resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 15 \text{ A}$	(-)	50	55	mΩ
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 15 \text{ A}$	4.5	9	_	S
Input capacitance	9	C _{iss}	\sim (7	/A	2030	_	
Reverse transfer capacitance		C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	Ĵ.	340	_	pF
Output capacitance		C _{oss}		_	1200	_	
Switching time	Rise time	tr	10 V V _{GS1} I _D = 15 A V _{OUT}	_	20		
	Turn-on time	t _{on}	$\begin{bmatrix} 0 \lor -1 & \Box & \Box & \Box \\ & G \circ & \Box & \Box & A \\ & & & & & \\ & & & & & \\ & & & & &$	_	40	\rightarrow	20
	Fall time	t _f		-(10		ns
	Turn-off time	t _{off}	$J_{Duty} \le 1\%, t_W = 10 \ \mu s$		40	/_	
Total gate charg gate-drain)	ge (gate-source plus	Qg		$\overline{\mathcal{A}}$	45	_	
Gate-source charge		Qgs	$V_{DD} \simeq 120 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 30 \text{ A}$		21	—	nC
Gate-drain ("miller") charge		Q _{gd}) -	24		

Note 4: Connect the S1 and S2 pins together, and ground them except during switching time measurement.

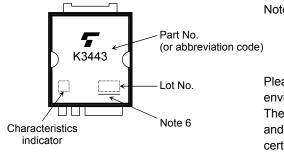
Source-Drain Diode Ratings and Characteristics (Note 5) (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1, Note 5)	IDR1		_	_	30	А
Pulse drain reverse current (Note 1, Note 5)	I _{DRP} 1				120	А
Continuous drain reverse current (Note 1, Note 5)	I _{DR} 2			_	1	А
Pulse drain reverse current (Note 1, Note 5)	1 _{DRP} 2	-			4	А
Forward voltage (diode)	V _{DS2F}	I _{DR1} = 30 A, V _{GS} = 0 V	_	_	-1.5	V
Reverse recovery time	∧ ^t rr	I _{DR} = 30 A, V _{GS} = 0 V,	_	250	_	ns
Reverse recovery charge	Qrr	dl _{DR} /dt = 100 A/μs	_	1.75	_	μC

Note 5: 1_{DR}1, 1_{DRP}1: Current flowing between the drain and the S2 pin. Ensure that the S1 pin is left open. I_{DR}2, I_{DRP}2: Current flowing between the drain and the S1 pin. Ensure that the S2 pin is left open.

Unless otherwise specified, connect the S1 and S2 pins together, and ground them.

Marking

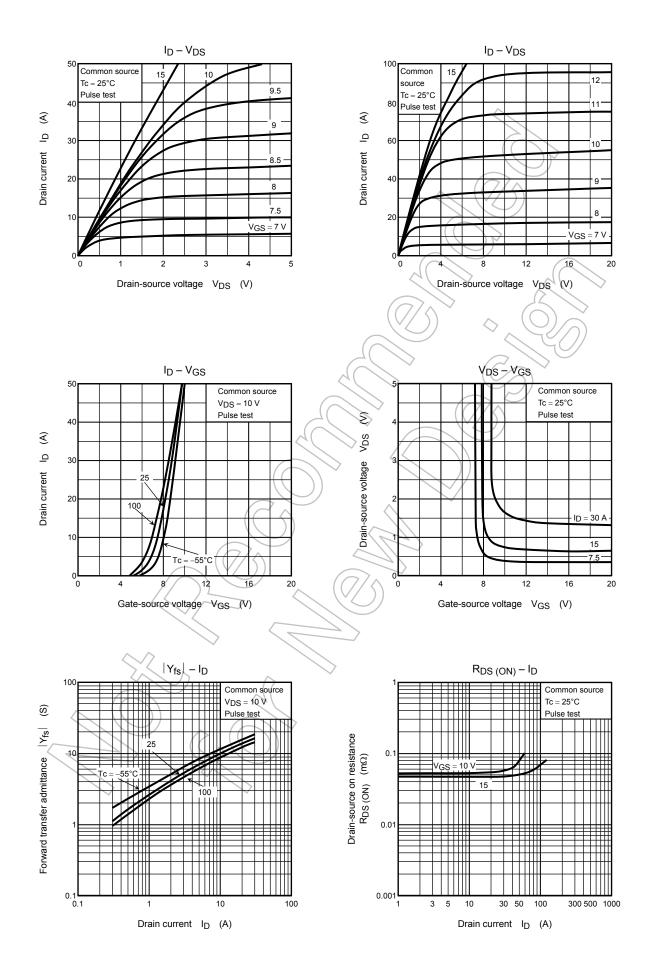


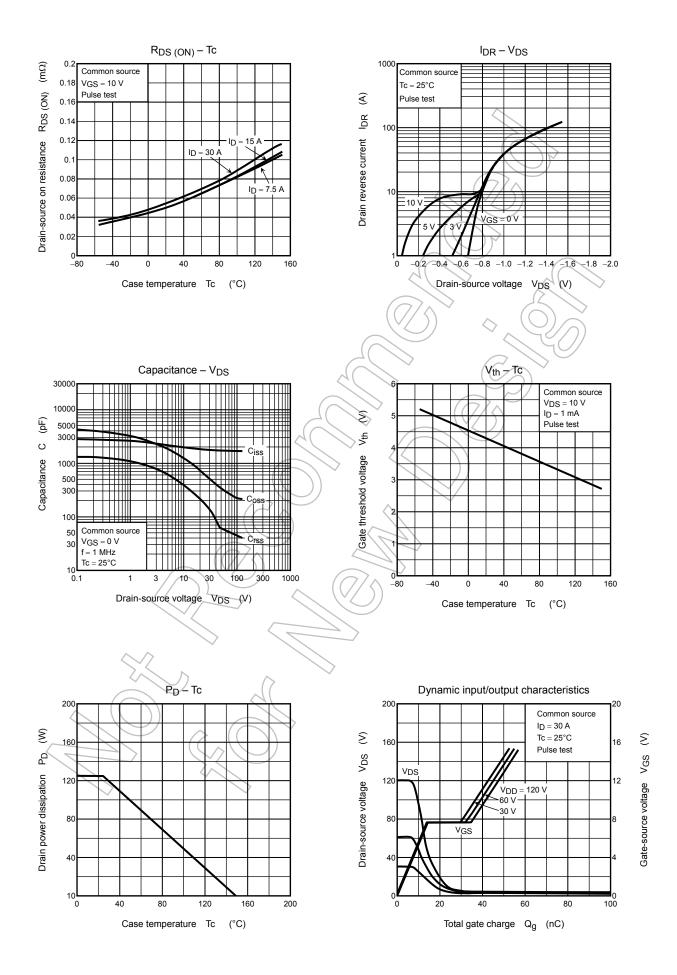
Note 6: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

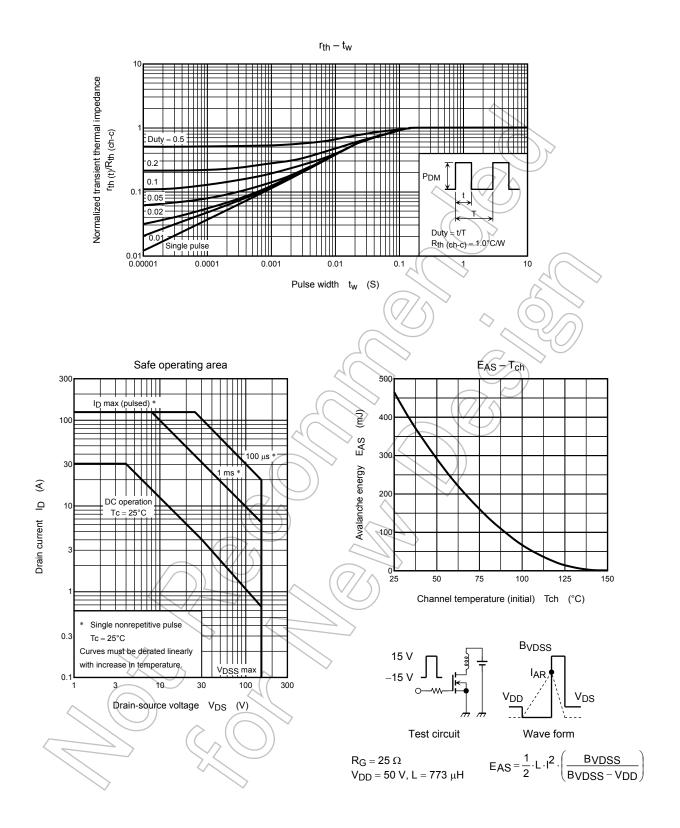
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

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